		1		2		3		4	
A	1	2	3	4	-	5		6	
	Pos.	Ref. C1, C8, aaa aaa aaa aaa	Q†y. 1	Name C		Value 2uF		Description Unpolarized capacitor	
В	2	C2, C6	2	С		100n		Unpolarized capacitor	
	3	СЗ,	1	С		66pF		Unpolarized capacitor	
	4	C4, C5	2	CP-Device		33u/25V			
	5	C7, C10	2	С		220р		Unpolarized capacitor	
	6	C8, C9	2	CP-Device		1000μ/25V			
	7	C11,	1	С		150pF		Unpolarized capacitor	
c	8	M1,	1	Oszi-Devices_tobiasfalk		0 szi			
ر	9	NG1 NG2	2	NG-Devices_tobiasfalk		NG			
	10	Q1, Q2, Q3	3	BC413		BC413		0.1A Ic, 30V Vce, Small Signal NPN Transistor, T0-92	
D	11	Q4, Q5	2	BC559		BC559		0.1A Ic, 30V Vce, PNP Small Signal Transistor, TO-92	
	12	Q15,	1	Q_NPN_Darlington_BCE		NPN BDW83		NPN Darlington transistor, base/collector/ emitter	
	13	Q16,	1	Q_PNP_Darlington_BCE		PNP BDW84		PNP Darlington transistor, base/collector/ emitter	
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A	Pos.			4 Name		5 Value		6 Description	
	14	R0,	1	Name R		0 R		Resistor	
	15	R1, R6, R7, R45	4	R	39		Resistor		
	16	R3,	1	R		470		Resistor	
В	17	R4, R5	2	R	120		Resistor		
	18	R8, R19 R11 5	3	R		1k		Resistor	
	19	R9,	1	R	10 k		Resistor		
	20	R10 R13	2	R	0,33R		Resistor		
H	21	R17,	1	R		510k		Resistor	
	22	R20,	1	R		39k		Resistor	
	23	R26,	1	R		47R		Resistor	
	24	R31 R32	2	R		3k9		Resistor	
	25	R40 R41	2	R	820		Resistor		
	26	RA1,	1	R		2k2		Resistor	
D	27	U1,	1	NE5532		NE5532		Dual Low-Noise Operational Amplifiers, DIP-8/SOIC-8	
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